NUS03-001

SEP 0 1 2005 W

August 11, 2005

To: Commissioner (September 1987)

P.O. Box 1450

Alexandria, VA 22313-1450

Fr:

Stephen B. Ackerman, Reg. No. 37,761

28 Davis Avenue

Poughkeepsie, N.Y. 12603

Subject:

Serial No.

10/802,563

03/17/04

Hong Yu Yu et al

"A THERMAL ROBUST SEMICONDUCTOR DEVICE USING HFN AS METAL GATE ELECTRODE AND THE MANUFACTURING PROCESS THEREOF"

Grp. Art Unit: 2823

SU C. KIM

## RESPONSE PATENT OFFICE ACTION

Dear Sir:

In response to the Office Action dated May 27, 2005, please amend the above-identified application for patent as follows:

## **CERTIFICATE OF MAILING**

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on August 29, 2005.

Rosemary L. S

L. S. Pike. Reg # 39,3

Signature \_

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NUS03-001

Amendments to the Specification begin on page 3 of this paper.

Amendments to the Claims are reflected in the listing of the Claims which begins on page 8 of this paper.

Amendments to the Drawings begin on page 16 of this paper and include an attached replacement sheet.

Remarks/Arguments begin on page 17 of this paper.

An Appendix including amended drawing figures is attached following page 22 of this paper.